# Advance Data Sheet September 2000

## microelectronics group



# R768-Type OC-768/STM-256 Lightwave Receiver



The R768 Receiver is manufactured in a 16-pin, pigtailed surface-mount metal package with a single-ended V-connector.

#### Features

- High data rate capability, 40 Gbits/s
- PIN photodetector
- Fully operational through the L-band (1.6 μm) wavelength range
- Single-mode fiber pigtail with FC/PC optical connector
- Operating case temperature range:
  0 °C to 65 °C
- Compact, butterfly package

#### **Applications**

- Line terminal equipment
- High-speed networks up to 40 Gbits/s
- SONET OC-768 and SDH STM-256 telecommunications applications
- Extended-reach datacom and telecom applications
- Digital video

## Description

#### **Receiver Operation**

The R768 40 Gbits/s fiber-optic receiver consists of a high-speed photodetector (PIN) and a wide-band linear preamp in a pigtailed surface-mount metal package with a single-ended V-connector. It is designed for use in single-mode, high-speed telecommunication applications at the SONET OC-768 and the ITU-T SDH STM-256 data rate of 42.5 Gbits/s.

The operating case temperature range for the receiver is 0 °C to 65 °C.

The receiver is manufactured in a compact, 16-pin surface-mount package with a single-mode optical fiber pigtail. The fiber pigtail is internally beveled for low return loss and is available with an FC-PC optical connector.

The received data is dc-coupled.

The receiver requires only a 6 V power supply for operation, plus an optional VADJUST from -1.0 V to +1.0 V (see pin descriptions). The photodiode requires a separate bias voltage: for the PIN, a nominal reverse bias of 4 V is required.

## **Pin Information**

#### Table 1. Pin Descriptions

Pin Number	Name				
1	Not Used				
2	GND				
3	Alternate PIN Bias				
4	GND				
5	GND				
6	GND				
7	VADJUST (optional)				
8	GND				
9	GND				
10	GND				
11	GND				
12	Vcc				
13	GND				
14	PIN Bias				
15	GND				
16	NC				

#### **Absolute Maximum Ratings**

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operations section of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect device reliability.

Parameter	Symbol	Min	Мах	Unit
Positive Supply Voltage	Vcc	5.0	7.0	V
Photodiode Forward Current*	IPD	—	1	mA
Maximum Reverse Bias	Vв	—	5	V
Optical Input Power, PIN	Рмах	_	8	dBm
Operating Case Temperature	Тс	0	65	°C
Storage Temperature	Tstg	-40	85	°C
Lead Soldering Temperature	_	_	250	°C
Lead Soldering Time	—	—	10	S

\* Device is normally reverse biased. Forward biasing the photodiode can compromise device performance and reliability.

## **Optical Characteristics**

#### **Table 2. Optical Characteristics** (TA = 25 °C)

Parameter	Symbol	Min	Тур	Max	Unit
Optical wavelength for Rated Sensitivity	λ	1.480	_	1.610	μm
Sensitivity, PIN	PLOW	—	-7	—	dBm
Maximum Optical Input Power, Average, PIN	Рнідн	—	3	—	dBm
Optical Return Loss	—	-27	-30	—	dBm
Responsivity of PIN, $\lambda = 1.55 \ \mu m$	<b>R</b> PIN	—	0.7	—	A/W
Total Dark Current	ID	—	0.5	—	μΑ
Polarization-dependent Loss	PDL	_	—	0.5	dB

## **Electrical Characteristics**

#### Table 3. Electrical Characteristics (TA = 25 °C)

Parameter	Symbol	Min	Тур	Max	Unit
dc Power Supply Voltages: Positive Supply PIN Bias Optional VADJUST	Vcc Vpin Vadj	5.5 3.5 –1.0	6.0 4.0 —	6.5 4.5 1.0	V V V
Positive dc Power Supply Current	Icc	—	80	150	mA
Power Dissipation	PDISS	—	—	0.975	W
Conversion Gain	—	—	60	—	V/W
Average Equivalent Input Noise Spectral Density	—			50	pA/√Hz
Low Frequency Cutoff (-3 dB)	f∟		100	—	kHz
Bandwidth	BW		45	—	GHz
Rolloff (3 dB + 5 GHz)	—		-10	—	dB
Peaking	—			2	dB
Deviation from Linear Phase: 100 kHz—25 GHz 25 GHz—40 GHz 40 GHz—50 GHz	_		10 20 40		deg deg deg
Output Return Loss: 100 kHz—20 GHz 25 GHz—40 GHz 40 GHz—50 GHz	S22			15 10 5	dB dB dB

## **Outline Diagram**

Dimensions are in millimeters.







#### **Ordering Information**

#### **Table 4. Ordering Information**

Description	Product Code	Photodiode	Connector	Comcode
R768-Type OC-768/STM-256 Lightwave Receiver	R768PGAA	PIN	FC	108894635
	R768PSAA	PIN	LC	108894643
	R768PDAA	PIN	SC	108727041
	R768PJAA	PIN	Test Ferrule	TBD

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